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PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Attn: OIPE

Izumi FUSEGAWA et al.

Application No.: 10/510,695

Docket No.: 121356

Filed: October 8, 2004

For: METHOD OF MANUFACTURING SILICON SINGLE CRYSTAL, SILICON
SINGLE CRYSTAL AND SILICON WAFER

REQUEST FOR CORRECTION OF PALM RECORDS

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

Attached is a photocopy of the original filing receipt on which errors have been corrected in red. These errors are being brought to the attention of the Patent and Trademark Office so that it may correct its records.

Respectfully submitted,

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WPB:PAC/nxy

Date: April 12, 2005

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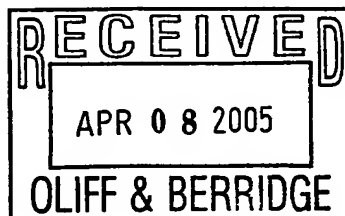
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APPL NO.	FILING OR 371 (c) DATE	ART UNIT	FIL FEE REC'D	ATTY. DOCKET NO	DRAWINGS	TOT CLMS	IND CLMS
10/510,695	10/08/2004	1765	950	121356	3	9	3

 25944
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CONFIRMATION NO. 3939

FILING RECEIPT



OC000000015631722

Date Mailed: 04/05/2005

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Assignment For Published Patent Application

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Power of Attorney: The patent practitioners associated with Customer Number 25944.

Domestic Priority data as claimed by applicant

This application is a 371 of PCT/JP03/05167 04/23/2003

Foreign Applications

JAPAN 2002-122250 04/24/2002

Projected Publication Date: 07/07/2005

Non-Publication Request: No

Early Publication Request: No

* PLEASE SEE PAGE 2 FOR CORRECTIONS TO THE TITLE *

Title

~~Method for producing silicon single crystal and, silicon single crystal and silicon wafer~~

Preliminary Class

METHOD OF MANUFACTURING SILICON SINGLE CRYSTAL, SILICON SINGLE CRYSTAL AND
SILICON WAFER

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